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Display apparatus, photoelectric conversion apparatus, electric equipment, illumination apparatus, moving body, and wearable device

Abstract

A display apparatus comprising a substrate in which a plurality of pixels are arranged is provided. Each of the plurality of pixels comprises a light emitting element arranged above a first surface of the substrate, and a light receiving element arranged between the first surface and a second surface of the substrate on an opposite side of the first surface. The light emitting element comprises a first electrode, a second electrode arranged between the first surface and the first electrode, and a light emitting layer arranged between the first electrode and the second electrode. In an orthogonal projection with respect to the first surface, the second electrode and the light receiving element at least partially overlap each other.

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Background/Summary

BACKGROUND OF THE INVENTION

Field of the Invention

(1) The present invention relates to a display apparatus, a photoelectric conversion apparatus, an electric equipment, an illumination apparatus, a moving body, and a wearable device.

Description of the Related Art

(2) There is an increasing interest in a display apparatus that uses a self-luminous light emitting element such as an organic electroluminescence (EL) element. Due to an image displayed on the display apparatus, a deterioration distribution of the light emitting element may be generated in a display region. Japanese Patent Laid-Open No. 2006-251201 describes that a light emitting element also functions as a light receiving element and detects the light emission amount of an adjacent light emitting element, and input video data for causing the light emitting element to emit light is corrected based on the detected light reception signal.

(3) When using a light emitting element as a light receiving element, due to an influence of light entering from the outside, the correction effect may be decreased.

SUMMARY OF THE INVENTION

(4) Some embodiments of the present invention provide a technique advantageous in detecting the luminance of a light emitting element.

(5) According to some embodiments, a display apparatus comprising a substrate in which a plurality of pixels are arranged, wherein each of the plurality of pixels comprises a light emitting element arranged above a first surface of the substrate, and a light receiving element arranged between the first surface and a second surface of the substrate on an opposite side of the first

surface, the light emitting element comprises a first electrode, a second electrode arranged between the first surface and the first electrode, and a light emitting layer arranged between the first electrode and the second electrode, and in an orthogonal projection with respect to the first surface, the second electrode and the light receiving element at least partially overlap each other, is provided.

(6) Further features of the present invention will become apparent from the following description of exemplary embodiments (with reference to the attached drawings).

Description

BRIEF DESCRIPTION OF THE DRAWINGS

- (1) FIG. 1 is a view showing an arrangement example of a display apparatus according to an embodiment;
- (2) FIG. 2 is a circuit diagram showing an arrangement example of a pixel of the display apparatus shown in FIG. 1;
- (3) FIG. 3 is a timing chart in one horizontal scanning period of the display apparatus shown in FIG. 1;
- (4) FIG. 4 is a timing chart in one vertical scanning period of the display apparatus shown in FIG. 1;
- (5) FIG. 5 is a plan view showing an arrangement example of the pixel of the display apparatus shown in FIG. 1;
- (6) FIG. 6 is a sectional view showing the arrangement example of the pixel of the display apparatus shown in FIG. 1;
- (7) FIG. 7 is a plan view showing an arrangement example of the pixel of the display apparatus shown in FIG. 1;
- (8) FIG. 8 is a sectional view showing the arrangement example of the pixel of the display apparatus shown in FIG. 1;
- (9) FIG. 9 is a plan view showing an arrangement example of the pixel of the display apparatus shown in FIG. 1;
- (10) FIG. 10 is a sectional view showing the arrangement example of the pixel of the display apparatus shown in FIG. 1;
- (11) FIG. 11 is a sectional view an arrangement example of the pixel of the display apparatus shown in FIG. 1;
- (12) FIGS. 12A to 12C are plan views showing an arrangement example of the pixel of the display apparatus shown in FIG. 1;
- (13) FIGS. 13A to 13C are plan views showing an arrangement example of the pixel of the display apparatus shown in FIG. 1;
- (14) FIGS. 14A to 14C are plan views showing an arrangement example of the pixel of the display apparatus shown in FIG. 1;
- (15) FIG. 15 is a plan view showing an arrangement example of the pixel of the display apparatus shown in FIG. 1;
- (16) FIG. 16 is a view showing an application example of the display apparatus of the embodiment;
- (17) FIG. 17 is a view showing an example of a photoelectric conversion apparatus using the display apparatus of the embodiment;
- (18) FIG. 18 is a view showing an example of an electric equipment using the display apparatus of the embodiment;
- (19) FIGS. 19A and 19B are views each showing an application example of the display apparatus of the embodiment;
- (20) FIG. 20 is a view showing an example of an illumination apparatus using the display apparatus

of the embodiment;

(21) FIG. 21 is a view showing an example of a moving body using the display apparatus of the embodiment; and

(22) FIGS. 22A and 22B are views each showing an example of a wearable device using the display apparatus of the embodiment.

DESCRIPTION OF THE EMBODIMENTS

(23) Hereinafter, embodiments will be described in detail with reference to the attached drawings. Note, the following embodiments are not intended to limit the scope of the claimed invention. Multiple features are described in the embodiments, but limitation is not made to an invention that requires all such features, and multiple such features may be combined as appropriate.

Furthermore, in the attached drawings, the same reference numerals are given to the same or similar configurations, and redundant description thereof is omitted.

(24) With reference to FIGS. 1 to 15, a display apparatus according to an embodiment of the present disclosure will be described. FIG. 1 is a schematic view showing an arrangement example of a display apparatus **101** of this embodiment. As shown in FIG. 1, the display apparatus **101** includes a pixel array **103**, and a driving circuit arranged around the pixel array **103**. The pixel array **103** includes a plurality of pixels **102** two-dimensionally arranged in a matrix. Each of the plurality of pixels **102** includes a light emitting element and a light receiving element. Although details will be described with reference to FIG. 2, in this embodiment, the light emitting element is a self-luminous element such as an organic EL element. In this case, a light emitting element **201** includes an organic layer including a light emitting layer between an anode and a cathode. The organic layer may include, in addition to the light emitting layer, one or more of a hole injection layer, a hole transport layer, an electron injection layer, and an electron transport layer, as appropriate.

(25) The driving circuit is a circuit for driving each pixel **102**. The driving circuit includes, for example, a vertical scanning circuit **104**, a signal output circuit **105**, and a readout circuit **106**. In the pixel array **103**, scanning lines **107** to **110** are arranged for each pixel row along a row direction (a lateral direction in FIG. 1). Further, in the pixel array **103**, a signal line **111** and a vertical output line **112** are arranged for each pixel column along a column direction (a vertical direction in FIG. 1).

(26) Each of the scanning lines **107** to **110** is connected to an output terminal of the vertical scanning circuit **104** in a corresponding pixel row. Each signal line **111** is connected to an output terminal of the signal output circuit **105** in a corresponding pixel column. Each vertical output line **112** is connected to an input terminal of the readout circuit **106** in a corresponding pixel row.

(27) When writing a video signal to each pixel **102** arranged in the pixel array **103**, a control signal is input from the vertical scanning circuit **104** to the scanning line **107**. Further, when writing the video signal to the pixel **102**, the signal output circuit **105** outputs a luminance signal having a voltage corresponding to luminance information.

(28) When a signal is output from each pixel **102** arranged in the pixel array **103**, the vertical scanning circuit **104** supplies various kinds of control signals to the scanning lines **108** to **110**. The pixel **102** connected to the scanning lines **108** to **110** supplied with the control signals outputs a pixel signal to the corresponding vertical output line **112**. When the vertical scanning circuit **104** sequentially inputs the control signals to the scanning lines **108** to **110**, the pixel signals are sequentially output from the respective pixels **102** to the vertical output lines **112**.

(29) FIG. 2 is a circuit diagram showing an arrangement example of the pixel **102** arranged in the display apparatus **101** shown in FIG. 1. As shown in FIG. 2, the pixel **102** includes the light emitting element **201**, a driving transistor **202**, a writing transistor **203**, a capacitive element **204**, a light receiving element **205**, a transfer transistor **206**, a reset transistor **207**, an amplification transistor **208**, and a selection transistor **209**. Here, a circuit including the driving transistor **202**, the writing transistor **203**, and the capacitive element **204**, which are arranged to drive the light

emitting element **201**, is sometimes referred to as a light emitting circuit. Further, a circuit including a transfer transistor **206**, the reset transistor **207**, the amplification transistor **208**, and the selection transistor **209**, which are arranged to drive the light receiving element **205**, is sometimes referred to as a light receiving circuit.

(30) In this embodiment, a case will be described in which the driving transistor **202** is connected to an anode of the light emitting element **201**, all transistors related to driving of the light emitting element **201** are p-type transistors, and all transistors related to driving of the light receiving element **205** are n-type transistors. However, the combination of the transistors is not limited to the arrangement shown in FIG. 2. The polarity and conductivity type of each of the light emitting element, the light receiving element, and the transistors may be reversed for some or all of them. The potential to be supplied and the connection may be changed as appropriate in accordance with the polarity and conductivity type of each of the light emitting element, the light receiving element, and the transistors. That is, the total number of the transistors and the capacitive element and the combination of the conductivity types of the transistors are merely examples, and can be changed as appropriate in accordance with specifications required for the display apparatus **101**.

(31) Here, in this specification, the expression that “a transistor is connected between an element A and an element B” represents a state in which one (a source or a drain) of two main terminals of the transistor is connected to the element A and the other of the two main terminals is connected to the element B. That is, the expression that “a transistor is connected between an element A and an element B” does not include a case in which a control terminal (gate electrode) of the transistor is connected to at least one of the element A and the element B.

(32) As a specific arrangement of the pixel **102**, one of two main terminals of the driving transistor **202** is connected to one (anode) of two main terminals of the light emitting element **201**. The other of the two main terminals of the driving transistor **202** is connected to a power supply potential **212** (for example, Vdd). Accordingly, it can be said that the driving transistor **202** is connected between the light emitting element **201** and the power supply potential **212**. The other (cathode) of the two main terminals of the light emitting element **201** is connected to a power supply potential **211** (for example, Vss).

(33) One of two main terminals of the writing transistor **203** is connected to a control terminal of the driving transistor **202**, and the other is connected to the signal line **111**. Accordingly, the writing transistor **203** is connected between the driving transistor **202** and the signal line **111**. A control terminal of the writing transistor **203** is connected to the scanning line **107**. The capacitive element **204**, which holds a luminance signal (luminance signal voltage Vsig) corresponding to the luminance of light emission of the light emitting element **201**, is connected between the control terminal of the driving transistor **202** and the other (source) of two main terminals.

(34) One of two main terminals of the transfer transistor **206** is connected to one (cathode) of main terminals of the light receiving element **205**, and the other is connected to a control terminal of the amplification transistor **208**. One of two main terminals of the amplification transistor **208** is connected to a power supply potential **213**, and the other is connected to one of two main terminals of the selection transistor **209**. The power supply potential **213** may be the same potential (for example, Vdd) as the power supply potential **212**, or may be different potential. One of two main terminals of the reset transistor **207** is connected to the control terminal of the amplification transistor **208** and the other of the two main terminals of the transfer transistor **206**, and the other of the two main terminals of the reset transistor **207** is connected to the power supply potential **213**. The other of the two main terminals of the selection transistor **209** is connected to the vertical output line **112**, and a control terminal of the selection transistor **209** is connected to the scanning line **110**. The other (the anode) of the two main terminals of the light receiving element **205** is connected to the power supply potential **211**. A capacitance **210** (floating diffusion capacitance) is connected to a connection node between the control terminal of the amplification transistor **208** and the other of the two main terminals of the reset transistor **207**. The capacitance **210** has a function

as a holding portion of electric charges generated by the light receiving element **205**. The capacitance **210** may be a parasitic capacitance of the transfer transistor **206**, the reset transistor **207**, the amplification transistor **208**, or a wiring pattern connecting them. In FIG. **2**, the capacitance **210** is shown as a capacitive element.

(35) FIG. **3** is a timing chart showing an operation example in one horizontal scanning period of the pixel **102** shown in FIG. **2**. Here, FIG. **3** shows a line-sequential light emitting operation and a line-sequential light receiving operation. Periods before time t_1 are a light emitting period of the light emitting element **201** and a light receiving period of the light receiving element **205** in the $(n-1)$ th frame. From time t_1 to time t_{10} , writing of luminance information to the light emitting element **201** in the n th frame is performed, and the light receiving element **205** outputs, to the vertical output line **112**, signal charges corresponding to the light emission amount of the light emitting element **201** in the $(n-1)$ th frame.

(36) At time t_1 , the vertical scanning circuit **104** makes the scanning line **109** transition from a Low signal to a High signal. This sets the reset transistor **207** in an ON state, and charges accumulated in the capacitance **210** are discharged to the power supply potential **213**.

(37) Then, at time t_2 , a luminance signal voltage V_{sig} corresponding to the luminance information is set to the signal line **111** from the signal output circuit **105**.

(38) When the luminance signal voltage V_{sig} is set to the signal line **111**, at time t_3 , the vertical scanning circuit **104** makes the scanning line **107** transition from a High signal to a Low signal. This sets the writing transistor **203** in an ON state, and the luminance signal voltage V_{sig} is written to the control terminal of the driving transistor **202**. With this, a driving current corresponding to the luminance signal voltage V_{sig} flows from the driving transistor **202** to the light emitting element **201**.

(39) Then, at time t_4 , the vertical scanning circuit **104** makes the scanning line **109** transition from the High signal to the Low signal. This sets the reset transistor **207** in an OFF state. With this, a reset of the capacitance **210** is completed.

(40) When the reset of the capacitance **210** is completed, at time t_5 , the vertical scanning circuit **104** makes the scanning line **110** transition from a Low signal to a High signal. This sets the selection transistor **209** in an ON state, and the amplification transistor **208** and the vertical output line **112** are electrically connected to each other. With this, a reset potential (N signal) of the capacitance **210** buffered by the amplification transistor **208** is output to the vertical output line **112**.

(41) Then, at time t_6 , the vertical scanning circuit **104** makes the scanning line **108** transition from a Low signal to a High signal. This sets the transfer transistor **206** in an ON state, and electric charges accumulated in the light receiving element **205** are transferred to the capacitance **210**. Since the light receiving element **205** photoelectrically converts and accumulates signal charges almost proportional to the light emission amount of the light emitting element **201**, data used to correct a deterioration or defect of the light emitting element **201** can be acquired by reading out the electric charges of the light receiving element **205**.

(42) At time t_7 , the vertical scanning circuit **104** makes the scanning line **108** transition from the High signal to the Low signal. This sets the transfer transistor **206** in an OFF state. With this, transfer of electric charges to the capacitance **210** is completed.

(43) At time t_8 , the signal charges accumulated in the light receiving element **205** are converted into a voltage (S signal) by the amplification transistor **208**, and read out from the vertical output line **112**. By calculating the difference between the N signal obtained at time t_5 and the S signal, a signal with a noise component suppressed can be acquired.

(44) Then, at time t_9 , the vertical scanning circuit **104** makes the scanning line **110** transition from the High signal to the Low signal. This sets the selection transistor **209** in an OFF state, and the electric connection between the vertical output line **112** and the amplification transistor **208** is disconnected.

(45) At time **t10**, the vertical scanning circuit **104** makes the scanning line **107** transition from the Low signal to the High signal. This sets the writing transistor **203** in an OFF state, and writing of the luminance signal voltage **Vsig** to the control terminal of the driving transistor **202** is completed. The potential corresponding to the luminance signal voltage **Vsig** is held in the capacitive element **204** connected between the gate and source of the driving transistor **202**.

(46) FIG. **4** is a timing chart showing an operation example in one vertical scanning period of the pixel **102** shown in FIG. **2**. At time **t11**, writing of the luminance signal voltage **Vsig** to the light emitting element **201** arranged in the first row and reading out of the N signal and S signal from the light receiving element **205** arranged in the first row are performed. At each time from time **t12** to time **tN**, similar to time **t11**, writing of the luminance signal voltage **Vsig** to the light emitting element **201** arranged in a corresponding row and reading out of the N signal and S signal from the light receiving element **205** arranged in the corresponding row are performed. Writing of the luminance signal voltage **Vsig** to the light emitting element **201** and reading out of the N signal and S signal from the light receiving element **205** are performed as described with reference to FIG. **3**.

(47) The signal output from the light receiving element **205** has a value almost corresponding to the light emission luminance of the light emitting element **201**. Therefore, by comparing the luminance information to the light emitting element **201** input to the display apparatus **101** with the signal output from the light receiving element **205**, information of a deterioration of the light emitting element **201**, an uneven luminance in a surface of the pixel array **103**, and the like can be acquired. By correcting data of the luminance information input to the display apparatus **101** using the information of the deterioration of the light emitting element **201**, the uneven luminance, and the like, it is possible to display an image in which the deterioration of the light emitting element **201**, the uneven luminance, and the like have been corrected. That is, it is possible to suppress a deterioration in image quality of the image displayed on the display apparatus **101**.

(48) In FIG. **4**, the driven row of the light emitting element **201** and the driven row of the light receiving element **205** are in synchronization with each other, but the present invention is not limited to this. For example, in the display apparatus **101**, when causing the light emitting element **201** to emit light at a high luminance, signal saturation may occur in the light receiving element **205** and correction data may not be obtained. In this case, the driving cycle of the light receiving element **205** may be made shorter than the driving cycle of the light emitting element **201** to shorten the signal accumulation time, thereby suppressing the signal saturation in the light receiving element **205**.

(49) Next, the layout of the pixel **102** of the display apparatus **101** that performs the operation as described above will be described. FIGS. **5** and **6** are a plan view and a sectional view showing an arrangement example of the pixel **102**, respectively. FIG. **6** shows a section taken along a line A-A' in the plan view of FIG. **5**. FIG. **5** shows a plane layout of one pixel **102** alone, but in practice, the layout shown in FIG. **5** is periodically repeated at a predetermined pitch in the row direction and the column direction.

(50) The driving transistor **202** is formed by including a gate electrode **502**, a p-type diffusion layer **512** (drain), and a p-type diffusion layer **522** (source). The writing transistor **203** is formed by including a gate electrode **503**, a p-type diffusion layer **513** (drain), and a p-type diffusion layer **523** (source). A gate electrode **506** indicates the gate electrode of the transfer transistor **206**, a gate electrode **507** indicates the gate electrode of the reset transistor **207**, a gate electrode **508** indicates the gate electrode of the amplification transistor **208**, and a gate electrode **509** indicates the gate electrode of the selection transistor **209**.

(51) The pixel **102** is formed on a substrate **610**. For example, a silicon substrate using silicon (Si) may be used as the substrate **610**. As shown in FIG. **6**, the light emitting element **201** is arranged above a surface **651** of two main surfaces of the substrate **610**, and the light receiving element **205** is arranged between the surface **651** and a surface **652** on the opposite side of the surface **651**.

(52) The light receiving element **205** is an embedded photodiode formed in a P.sup.+ -well **601** of

the substrate **610** and including a p-type semiconductor region **603** in contact with the surface **651** of the substrate **610**, and an n-type semiconductor region **604** provided below the p-type semiconductor region **603**. The semiconductor region **604** is an electric charge accumulation layer for accumulating signal charges (electrons) generated in the light receiving element **205**.

(53) An interlayer insulating film **622** is arranged on the surface **651** of the substrate **610**. One or more metal wiring layers **623** are arranged in the interlayer insulating film **622**. In the arrangement shown in FIG. **6**, three metal wiring layers **623** are arranged. However, the present invention is not limited to this, and the number of the metal wiring layers **623** may be two or less, or four or more. Conductive plugs **624** are arranged, as appropriate, between the metal wiring layers **623**, between the metal wiring layer **623** and the above-described transistor or the like formed in the substrate **610**, and between the metal wiring layer **623** and the light emitting element **201**, and electrically connected to each other. Various kinds of dielectric materials such as silicon oxide and silicon nitride are used for the interlayer insulating film **622**. Not only a nonorganic material but also an organic material may be used in the interlayer insulating film **622**. Different materials may be used for the interlayer insulating film **622** in accordance with the distance from the surface **651** of the substrate **610**. That is, the interlayer insulating film **622** may have a stacked structure. For example, copper (Cu), tungsten (W), aluminum (Al), and the like are used for the metal wiring layer **623** and the conductive plug **624**.

(54) On the side of the surface **651** of the substrate **610**, an n-type transistor (for example, the transfer transistor **206**) for driving the light receiving element **205**, and p-type transistors (for example, the driving transistor **202** and the writing transistor **203**) for driving the light emitting element **201** formed in an n-type semiconductor well **602** are arranged. Each transistor may be a CMOS transistor formed by a general CMOS process.

(55) The capacitive element **204** has a structure including the interlayer insulating film **622** (for example, a silicon oxide film) between an electrode **504** and an electrode **514**. The electrode **504** is connected to the p-type diffusion layer **522** (source) of the driving transistor **202**, and the electrode **514** is connected to the gate electrode **502** of the driving transistor **202**.

(56) The light emitting element **201** includes an electrode **620** (cathode), an electrode **501** (anode) arranged between the surface **651** of the substrate **610** and the electrode **620**, and a light emitting layer **621** arranged between the electrode **620** and the electrode **501**. As shown in FIG. **6**, the electrode **620** and the light emitting layer **621** may be shared by multiple pixels **102**. For example, the electrode **620** and the light emitting layer **621** may be integrally formed over the entire surface of the pixel array **103**. On the other hand, the electrode **501** is arranged for each light emitting element **201** (pixel **102**), and can be referred to as an individual electrode. The light emission position and light emission shape of the light emitting element **201** can be determined by the electrode **501** arranged for each light emitting element **201** (pixel **102**). A transparent conductive material can be used for the electrode **620** to transmit light generated in the light emitting layer **621**. As the transparent conductive material, a metal oxide such as tin oxide, zinc oxide, indium oxide, indium tin oxide (ITO), or indium zinc oxide can be used. For the electrode **501**, for example, a metal material such as tungsten (W), aluminum (Al), platinum (Pt), or palladium (Pd) is used. The above-described interlayer insulating film **622** is arranged between the surface **651** of the substrate **610** and the electrode **501**. Further, in this embodiment, a bank **625** formed of a dielectric is arranged so as to cover the outer edge of the electrode **501**. The bank **625** suppresses that a current flowing between the electrode **501** and the electrode **620** leaks to the adjacent pixel **102**.

(57) As shown in FIGS. **5** and **6**, in an orthogonal projection with respect to the surface **651** of the substrate **610**, the electrode **501** and the light receiving element **205** at least partially overlap each other. By arranging the electrode **501** above the light receiving element **205** so as to overlap each other, an influence caused by external light entering the light receiving element **205** can be reduced. Light emitted by the light emitting element **201** includes a component which propagates to the outside (air) from the display apparatus **101**, and a component which is reflected due to a reflective

index difference between the light emitting layer **621** and the electrode **620** or between the electrode **620** and air (when a protection layer, a color filter, or the like exists on the electrode **620**, between the electrode **620** and each layer) and returns to the light emitting layer **621** side. As shown in FIG. **6**, part **650** of the reflected component (reflected light) passes through a region where the electrode **501** and the light receiving element **205** do not overlap each other in the orthogonal projection with respect to the surface **651** of the substrate **610**, and enters the light receiving element **205**. Since the part **650** of the reflected light corresponding to the luminance of the light emitting element **201** enters the light receiving element **205**, a signal output corresponding to the luminance of the light emitting element **201** can be obtained from the light receiving element **205**.

(58) As described in Japanese Patent Laid-Open No. 2006-251201, when a light emitting element also functions as a light receiving element, for example, the light emitting element may be influenced by external light while it emits light at a low luminance, so the light emission amount of the light emitting element may not be accurately estimated. This can cause a degradation in accuracy of correction based on a detected signal. On the other hand, in this embodiment, in the orthogonal projection with respect to the surface **651** of the substrate **610**, the electrode **501** and the light receiving element **205** overlap each other. In addition, in an orthogonal projection with respect to a surface (section) orthogonal to the surface **651** of the substrate **610**, the light emitting element **201** and the light receiving element **205** do not overlap each other. Accordingly, it is possible to obtain a signal corresponding to the light emitted by the light emitting element **201** while suppressing an influence of external light entering the light receiving element **205**. Further, in the arrangement shown in FIGS. **5** and **6**, in the orthogonal projection with respect to the surface **651** of the substrate **610**, the light receiving element **205** and the capacitive element **204** of the light emitting circuit are arranged at positions which do not overlap each other. Accordingly, of the light emitted by the light emitting element **201**, the part **650** of the reflected light easily enters the light receiving element **205** as compared to a case in which the light receiving element **205** and the capacitive element **204** overlap each other. That is, by using the structure of the pixel **102** shown in this embodiment, it becomes possible to effectively perform correction of a deterioration of the light emitting element **201** and an uneven luminance in the surface of the pixel array **103**. As a result, the image quality of a display image displayed on the display apparatus **101** can be improved.

(59) Next, with reference to FIGS. **7** and **8**, a modification of the pixel **102** will be described. FIG. **7** is a plan view of the pixel **102**, and FIG. **8** is a sectional view taken along a line A-A' in FIG. **7**. A description will be given while focusing on the arrangement different from the layout shown in FIGS. **5** and **6**. In the arrangement shown in FIGS. **5** and **6**, the light receiving element **205** is arranged between the light emitting elements **201** adjacent to each other. Therefore, light from the adjacent light emitting element **201** may enter the light receiving element **205** and be detected by the light receiving element **205**.

(60) To prevent this, as shown in FIGS. **7** and **8**, in an orthogonal projection with respect to the surface **651** of the substrate **610**, a light shielding layer **701** is arranged in a region of the interlayer insulating film **622** which overlaps an outer edge portion of each pixel **102** of the plurality of pixels **102**. By arranging the light shielding layer **701** between the pixels **102** adjacent to each other, an effect of reducing an optical crosstalk caused by light emitted by the light emitting element **201** entering the light receiving element **205** of the adjacent pixel **102** can be obtained.

(61) The light shielding layer **701** can be formed of the same material as the materials of the metal wiring layer **623** and the conductive plug **624**. That is, the light shielding layer **701** can be simultaneously formed when forming the metal wiring layer **623** and the conductive plug **624**. By using the process as described above, an increase in the number of steps caused by providing the light shielding layer **701** can be suppressed. The light shielding layer **701** may be formed such that, in a direction crossing the surface **651** of the substrate **610**, the conductive plugs **624** connect from

the metal wiring layer **623** immediately above the substrate **610** to the pattern in the same layer as the electrode **501** of the light emitting element **201**.

(62) With reference to FIGS. **9** and **10**, another modification of the pixel **102** will be described. FIG. **9** is a plan view of the pixel **102**, and FIG. **10** is a sectional view taken along a line A-A' in FIG. **9**. A description will be given while focusing on the arrangement different from the layout shown in FIGS. **7** and **8**. In the arrangement shown in FIG. **7**, it is possible to suppress an optical crosstalk between the pixels **102** adjacent to each other, but reflected light from the light shielding layer **701** may enter a region other than the light receiving element **205**, and the sensitivity of the light receiving element **205** may decrease.

(63) To prevent this, as shown in FIGS. **9** and **10**, in an orthogonal projection with respect to the surface **651** of the substrate **610**, an optical waveguide **901** is arranged in a region of the interlayer insulating film **622** which overlaps the light receiving element **205** in the pixel **102**. The optical waveguide **901** is arranged such that a bottom portion on the side of the substrate **610** faces the light receiving element **205**. The optical waveguide **901** is obtained by forming, into a conical trapezoid shape, a material having a higher refractive index than the surrounding interlayer insulating film **622**, and has a function of guiding, to the light receiving element **205**, the part **650** of reflected light of light emitted by the light emitting element **201**. For example, when silicon oxide or the like is used for the interlayer insulating film **622**, a material such as silicon nitride may be used for the optical waveguide **901**.

(64) By arranging the optical waveguide **901**, it becomes possible to efficiently guide the light reflected by the light shielding layer **701** to the light receiving element **205**. With this, the sensitivity of the light receiving element **205** to light emitted from the light emitting element **201** can be improved. As a result, an influence of external light to the light receiving element **205** can be reduced, so that the light emission luminance of the light emitting element **201** to be detected can be detected with a high accuracy.

(65) In the structure of the pixel **102** described so far, the light emitting circuit for driving the light emitting element **201** and the light receiving circuit for driving the light receiving element **205** are arranged in one substrate **610**. Since the light emitting circuit including the driving transistor **202** and the like and the light receiving circuit including the transfer transistor **206** and the like are arranged with respect to one substrate **610**, miniaturization of the pixel **102** is limited. Now, achieving miniaturization of the pixel **102** by distributing and arranging the elements forming the light receiving circuit and the elements forming the light emitting circuit in two substrates will be described.

(66) FIG. **11** is a sectional view of the pixel **102** of the display apparatus **101** having a structure in which two substrates including the substrate **610** and a substrate **660** are stacked on each other. As in the arrangement described above, for example, a silicon substrate using silicon (Si) is used as the substrate **610**. As the substrate **660** arranged so as to face a surface **652** of the substrate **610**, for example, silicon (Si), glass, or the like may be used. In this embodiment, similar to the substrate **610**, a silicon substrate using silicon (Si) is used as the substrate **660**.

(67) The pixel **102** shown in FIG. **11** includes the light emitting element **201** arranged on the surface **651** of the substrate **610**, and the light receiving element **205** arranged between the surface **651** and the surface **652** of the substrate **610**. The light emitting element **201** includes the electrode **620**, the electrode **501** arranged between the surface **651** of the substrate **610** and the electrode **620**, and the light emitting layer **621** arranged between the electrode **620** and the electrode **501**. As in the respective arrangements describe above, the electrode **620** and the light emitting layer **621** may be shared by multiple pixels **102**, and the electrode **501** may be divided for each light emitting element **201** (pixel **102**), as shown in FIG. **11**. Further, as in the arrangements described above, the bank **625** formed of a dielectric may be arranged so as to cover the outer edge of the electrode **501**. An interlayer insulating film **627**, which makes the substrate **610** and the electrode **501** electrically independent of each other, can be arranged between the substrate **610** and the electrode **501**.

(68) The light receiving element **205** is arranged in the substrate **610**. As shown in FIG. **11**, the transfer transistor **206** is arranged on the surface **652** of the substrate **610**. Also in this embodiment, in an orthogonal projection with respect to the surface **651** of the substrate **610**, the electrode **501** and the light receiving element **205** at least partially overlap each other.

(69) The interlayer insulating film **622** is arranged on the surface **652** of the substrate **610** on the side of the substrate **660**, and one or more metal wiring layers **623** are arranged in the interlayer insulating film **622**. The conductive plugs **624** are arranged, as appropriate, between the metal wiring layers **623**, between the metal wiring layer **623** and the transistor or the like formed in the substrate **610**, and between the metal wiring layer **623** and the light emitting element **201**, and electrically connected to each other. The substrate **660** includes a surface **661** on the substrate **610** side of the substrate **660**, and a surface **662** on the opposite side of the surface **661**. An interlayer insulating film **672** is arranged on the surface **661** of the substrate **660**, and one or more metal wiring layers **673** are arranged in the interlayer insulating film **672**. Conductive plugs **674** are arranged, as appropriate, between the metal wiring layers **673**, and between the metal wiring layer **673** and the transistor or the like formed in the substrate **660**, and electrically connected to each other.

(70) Various kinds of dielectric materials such as silicon oxide and silicon nitride are used for the interlayer insulating films **622** and **672**. Not only a nonorganic material but also an organic material may be used for the interlayer insulating films **622** and **672**. Different materials may be used for the interlayer insulating films **622** and **672** in accordance with the distance from the surface **651** of the substrate **610**. That is, each of the interlayer insulating films **622** and **672** may have a stacked structure. For example, copper (Cu), tungsten (W), aluminum (Al) and the like are used for the metal wiring layers **623** and **673** and the conductive plugs **624** and **674**.

(71) The metal wiring layer **623** of the substrate **610** and the metal wiring layer **673** of the substrate **660** are electrically connected to each other by a direct joint between the metal wiring layer **623** and the metal wiring layer **673** in some region. For example, the metal wiring layer **623** in the uppermost layer and the metal wiring layer **673** in the uppermost layer may be electrically connected by Cu—Cu joint.

(72) An n-type transistor (for example, the transfer transistor **206**) for driving the light receiving element **205** formed in the substrate **610** is arranged on the side of the surface **652** of the substrate **610**. P-type transistors (for example, the driving transistor **202** and the writing transistor **203**) for driving the light emitting element **201** formed in an n-type well are arranged on the side of the surface **661** of the substrate **660**. Each transistor may be a CMOS transistor formed by a general CMOS process. The thickness of a gate insulating film of the transistor such as the transfer transistor **206** of the light receiving circuit arranged in the substrate **610** and the thickness of a gate insulating film of the transistor such as the driving transistor **202** of the light emitting circuit arranged in the substrate **660** may be equal to each other, or may be different from each other. In order to form the transistors in the two substrates **610** and **660**, each transistor is assigned to one of the two substrates **610** and **660** in accordance with a specification required for each transistor. With this, the transistors having different gate insulating film thicknesses can be easily formed.

(73) In this embodiment, the transistors of the light receiving circuit for driving the light receiving element **205** are arranged in the substrate **610**, and the transistors of the light emitting circuit for driving the light emitting element **201** are arranged in the substrate **660**. However, the present invention is not limited to this. Some transistors forming the light emitting circuit may be arranged in the substrate **610**, and some transistors forming the light receiving circuit may be arranged in the substrate **660**. In accordance with specifications of the pixel **102** of the display apparatus **101** and specifications required for the respective transistors forming the light receiving circuit and the light emitting circuit, the respective components are distributed and arranged in the two substrates **610** and **660**, as appropriate.

(74) FIGS. **12A** to **12C** are plan views corresponding to one pixel **102** of the display apparatus **101**

shown in FIG. 11. In practice, the layout shown in FIGS. 12A to 12C is periodically repeated at a predetermined pitch in the row direction and the column direction.

(75) FIG. 12A shows an example of the plane arrangement of the light emitting circuit (the driving transistor 202, the writing transistor 203, and the capacitive element 204) for driving the light emitting element 201 arranged in the substrate 660. The driving transistor 202 is formed by including the gate electrode 502, the p-type diffusion layer 512 (drain), and the p-type diffusion layer 522 (source). The writing transistor 203 is formed by including the gate electrode 503, the p-type diffusion layer 513 (drain), and the p-type diffusion layer 523 (source). The capacitive element 204 is arranged so as to partially overlap the driving transistor 202 and the writing transistor 203 in an orthogonal projection with respect to the surface 661 of the substrate 660.

(76) FIG. 12B shows an example of the plane arrangement of the light receiving element 205 and the light receiving circuit (the transfer transistor 206, the reset transistor 207, the amplification transistor 208, and the selection transistor 209) for driving the light receiving element 205, which are arranged in the substrate 610. The gate electrode 506 indicates the gate electrode of the transfer transistor 206, the gate electrode 507 indicates the gate electrode of the reset transistor 207, the gate electrode 508 indicates the gate electrode of the amplification transistor 208, and the gate electrode 509 indicates the gate electrode of the selection transistor 209.

(77) In an orthogonal projection with respect to the surface 651 of the substrate 610, the electrode 501 of the light emitting element 201 and the light receiving element 205 at least partially overlap each other. By arranging the electrode 501 above the light receiving element 205, as in the respective arrangements described above, an influence of external light to the light receiving element 205 can be suppressed.

(78) FIG. 12C shows a relationship obtained by overlapping the plan view of FIG. 12A and the plan view of FIG. 12B each other and stacking the respective elements. The capacitive element 204 of the light emitting circuit is arranged between the surface 652 of the substrate 610 and the surface 661 of the substrate 660. As shown in FIG. 12C, in the orthogonal projection with respect to the surface 651 of the substrate 610, the light receiving element 205 and the capacitive element 204 may at least partially overlap each other.

(79) Light emitted by the light emitting element 201 includes a component which propagates to the outside (air) from the display apparatus 101, and a component which is reflected due to a reflective index difference between the light emitting layer 621 and the electrode 620 or between the electrode 620 and air (when a protection layer, a color filter, or the like exists on the electrode 620, between the electrode 620 and each layer) and returns to the light emitting layer 621 side. Part of the reflected component (reflected light) passes through a region where the electrode 501 and the light receiving element 205 do not overlap each other in the orthogonal projection with respect to the surface 651 of the substrate 610, and enters the light receiving element 205. Since the part of the reflected light corresponding to the luminance of the light emitting element 201 enters the light receiving element 205, a signal output corresponding to the luminance of the light emitting element 201 can be obtained from the light receiving element 205.

(80) Also in the display apparatus 101 including the pixel 102 miniaturized by stacking the substrate 610 and the substrate 660 shown in FIGS. 11 and 12A to 12C, it is possible to obtain a signal corresponding to the light emitted by the light emitting element 201 while suppressing an influence of external light entering the light receiving element 205. That is, by using the structure of the pixel 102 shown in FIGS. 11 and 12A to 12C, it becomes possible to effectively perform correction of a deterioration of the light emitting element 201 and an uneven luminance in the surface of the pixel array 103. As a result, the image quality of a display image displayed on the display apparatus 101 can be improved.

(81) Next, a modification of the pixel 102 shown in FIGS. 12A to 12C will be described using FIGS. 13A to 13C. When the occupied area of the light receiving circuit in the substrate 610 is compared to the occupied area of the light emitting circuit in the substrate 660, in the orthogonal

projection with respect to the surface **651** of the substrate **610**, the area occupied by the light receiving element **205** and the light receiving circuit can be larger than the area occupied by the light emitting circuit. This is because the light receiving element **205** requires a relatively large area. Therefore, reducing the number of the elements of the light receiving circuit functions effectively to reduce the area of the pixel **102**.

(82) FIG. **13A** shows an example in which the light emitting circuit shown in FIG. **12A**, which is used to drive the light emitting element **201**, is shown for each of three elements (for example, a light emitting circuit for a red light emitting element, a light emitting circuit for a green light emitting element, and a light emitting circuit for a blue light emitting element). In this case, as shown in a plan view of FIG. **13B**, light receiving elements **205a** to **205c** and transfer transistors **206a** to **206c** (shown as gate electrodes **506a** to **506c** in FIG. **13B**) corresponding to the light receiving elements **205a** to **205c**, respectively, are arranged independently. On the other hand, by sharing the reset transistor **207**, the amplification transistor **208**, and the selection transistor **209** (shown as the gate electrodes **507** to **509**, respectively, in FIG. **13B**) after the capacitance **210** (floating diffusion capacitance) in the plurality of pixels **102**, the area of the light receiving circuit can be reduced. FIG. **13C** shows a relationship obtained by overlapping the plan view of FIG. **13A** and the plan view of FIG. **13B** each other and stacking the respective elements.

(83) As has been described above, the light receiving elements **205** (the light receiving elements **205a** to **205c** in the arrangement shown in FIG. **13B**) arranged in two or more pixels **102** may share a single light receiving circuit (the reset transistor **207**, the amplification transistor **208**, and the selection transistor **209** in the arrangement shown in FIG. **13B**). Further, in this case, the two or more pixels **102** sharing the single light receiving circuit may be pixels that emit light of the same color, or may be pixels that emit light of different colors. Here, light emission of different colors may mean that the light emitting layers **621** themselves of the light emitting elements **201** emit light of different colors, respectively. Alternatively, the light emitting layers **621** emit light of the same color, but color filters or the like may be arranged on the light emitting layers **621**. With this, the pixels **102** of the display apparatus **101** may emit light of different colors, respectively.

(84) For the pixels **102** that emit light of different colors, the luminance ratio for achieving white balance changes in accordance with the color temperature. As the color temperature increases, the luminance of blue increases and the luminance of red decreases. When the color temperature is high, the luminance of red becomes lower than the luminances of other colors. Accordingly, the amount of signal charges accumulated in the light receiving element **205**, which detects the luminance of red light, is small, so that the correction accuracy may decrease as compared to the other colors. In order to prevent this, the sensitivity of the light receiving element **205** corresponding to each color may be adjusted in accordance with the color temperature. The display apparatus **101** may include two or more (for example, three kinds including red light emission, green light emission, and blue light emission) pixels **102** that emit light of different colors, respectively, and the light receiving sensitivity of the light receiving element **205** arranged in a given pixel **102** may be different from the light receiving sensitivity of the light receiving element **205** arranged in the pixel that emit light of color different from that of the given pixel **102**.

(85) For example, in the pixels **102** having different light emission colors, the areas of the light receiving elements **205** may be different from each other. The area of the light receiving element **205** can be designed, as appropriate, in accordance with the designed white balance of the display apparatus **101**. For the display apparatus **101** capable of white balance adjustment, by employing an arrangement in which the amplification ratio of an amplifier arranged in the readout circuit **106** can be adjusted as appropriate, the light receiving sensitivity of the light receiving element **205** can be changed. Particularly, by setting the sensitivities of the light receiving elements **205** in the reverse order of the light emission intensities of respective colors defined by the white balance, it is possible to prevent a decrease in correction accuracy for a deterioration of the light emitting element **201**, an uneven luminance in the surface of the pixel array **103**, and the like.

(86) Next, another modification of the pixel **102** shown in FIGS. **12A** to **12C** will be described using FIGS. **14A** to **14C**. When the occupied area of the light receiving circuit in the substrate **610** is compared to the occupied area of the light emitting circuit in the substrate **660**, the area occupied by the light receiving element **205** and the light receiving circuit can be larger than the area occupied by the light emitting circuit. Hence, in order to increase the resolution of the display apparatus **101**, the repeating pitch of the light receiving circuit may be different from the repeating pitch of the light emitting circuit.

(87) FIG. **14A** shows an example in which the light emitting circuit shown in FIG. **12A**, which is used to drive the light emitting element **201**, is shown for each of three elements (for example, a light emitting circuit for a red light emitting element, a light emitting circuit for a green light emitting element, and a light emitting circuit for a blue light emitting element). In this case, as shown in FIG. **14B**, with respect to the light emitting circuits for driving the three light emitting elements **201**, one light receiving element **205** and one light receiving circuit (the transfer transistor **206**, the reset transistor **207**, the amplification transistor **208**, and the selection transistor **209** shown as the gate electrodes **506** to **509**, respectively, in FIG. **14B**) are arranged. That is, the plurality of pixels **102** may share one light receiving element **205** and one light receiving circuit. When the light receiving circuit and the light emitting circuit are arranged as described above, the repeating pitch of the light emitting circuit is different from the repeating pitch of the light receiving circuit. FIG. **14C** shows a relationship obtained by overlapping the plan view of FIG. **14A** and the plan view of FIG. **14B** each other and stacking the respective elements.

(88) In the arrangement shown in FIGS. **14A** to **14C**, the single light receiving element **205** detects the luminances of the three light emitting elements **201**. For example, when performing correction of a display image, a combined light amount of the three light emitting elements **201** is read out as a signal output (output image) from the light receiving circuit. Then, an image to be displayed and the output image are compared to calculate the difference therebetween. With this, correction data for a deterioration of each light emitting element **201** or the like can be obtained. Further, for example, when activating the display apparatus **101**, the pixel **102** for a specific color is caused to emit light, and the luminance thereof is detected by the light receiving element **205**. By repeating this operation for each color, the light emission amount with respect to input data to the light emitting element **201** of the pixel **102** can be acquired, and a correction coefficient for input data to the display apparatus **101** upon displaying an image can be acquired.

(89) Here, if the luminance of light emission of the light emitting element **201** is extremely low, the incident light amount to the light receiving element is small. In this case, a problem can occur that the light receiving element is easily influenced by noise such as external light, so the sufficient correction accuracy cannot be maintained. Further, if the luminance of light emission of the light emitting element is low, an output signal of the light receiving element **205** rises slowly (the response speed decreases). Accordingly, a problem also occurs that the time until luminance measurement increases. If the measurement time by the light receiving element **205** is short, the light emission luminance may be measured before the light emitting element **201** reaches the light emission luminance corresponding to the input data. As a result, correction may not be performed correctly. A structure of the electrode **501** for solving the above-described problems will be described using FIG. **15**.

(90) In FIG. **15**, an opening **551** is provided in the electrode **501** of the light emitting element **201** shown in the plan view of FIG. **12B**. The opening **551** may be filled with a part of the light emitting layer **621** or a light transmissive member. When the light emitting element **201** emits light, part of the light emitted by the light emitting element **201** passes through the opening **551** and enters the light receiving element **205**. Therefore, even when the luminance of the light emitting element **201** is low, the light amount entering the light receiving element **205** increases as compared to the electrode **501** shown in FIG. **12B**. Thus, the accuracy of correction data can be maintained. Further, the light receiving sensitivity of the light receiving element **205** may be changed for each color

described above by changing the size of the opening **551**.

(91) When the opening **551** is provided in the electrode **501** and filled with a part of the light emitting layer **621** or a light transmissive member as shown in FIG. **15**, a step can be formed in a peripheral edge portion of the opening **551**. If a disconnection or the like occurs in the light emitting layer **621** due to this step, this may affect the reliability of the display apparatus **101** (light emitting element **201**). In order to decrease the step formed in the peripheral edge portion of the opening **551**, the electrode **501** may have a stacked structure of a transparent electrode and a light shielding film such as a metal layer in which the opening **551** is provided. The metal layer functions as a light shielding film even when the film thickness is relatively small. For example, by stacking a transparent electrode on the metal layer so as to achieve a predetermined resistance value, the step of the opening **551** can be decreased.

(92) Alternatively, a structure may be employed in which no opening **551** is provided but a material that transmits at least part of the light emitted by the light emitting element **201** is used as the electrode **501**. That is, the electrode **501** may transmit part of the light generated in the light emitting layer. A metal oxide such as tin oxide, zinc oxide, indium oxide, indium tin oxide (ITO), or zinc indium oxide can be used as a transparent material that can be employed as the electrode **501**, but the present invention is not limited to this.

(93) In order to obtain information used to correct a deterioration of the light emitting element **201** or the like while preventing a decrease in light amount emitted from the display apparatus **101** and an influence of external light, the light transmittance of the electrode **501** is not necessarily a high transmittance but may be a relatively low transmittance. For example, the light transmittance of the electrode **501** may be 20% or less, or may be 10% or less. For the display apparatus **101** having a luminance of about 500 cd/m.^{sup.2}, if the light transmittance of the electrode **501** is 1% or more, information required for correction of the light emitting element **201** can be obtained without being buried in noise of the light receiving element **205**. That is, the transmittance of the electrode **501** to light generated in the light emitting layer **621** may be 1% or more and 20% or less.

(94) As has been described above using FIGS. **12A** to **15**, by using the stacked structure of the substrates **610** and **660**, while suppressing an influence of external light, it is possible to reduce (miniaturize) the area of the pixel **102** as compared to a case of using the single substrate **610**. As a result, increasing the resolution of the display apparatus **101** can be achieved.

(95) Here, an actual application example of the display apparatus **101** of this embodiment, and examples in which the display apparatus **101** is applied to a photoelectric conversion apparatus, an electronic equipment, an illumination apparatus, a moving body, and a wearable device will be described using FIGS. **16** to **22B**. In addition, the display apparatus **101** is applicable to the exposure light source of an electrophotographic image forming apparatus, the backlight of a liquid crystal display apparatus, a light emitting device including a color filter in a white light source, and the like. The display apparatus **101** may be an image information processing apparatus that includes an image input unit for inputting image information from an area CCD, a linear CCD, a memory card, or the like, and an information processing unit for processing the input information, and displays the input image on a display unit. In addition, a display unit included in a camera or an inkjet printer may have a touch panel function. The driving type of the touch panel function may be an infrared type, a capacitance type, a resistive film type, or an electromagnetic induction type, and is not particularly limited. The display apparatus may be used for the display unit of a multifunction printer.

(96) FIG. **16** is a schematic view showing an application example of a display apparatus using the display apparatus **101** of this embodiment. A display apparatus **1000** may include, between an upper cover **1001** and a lower cover **1009**, a touch panel **1003**, a display panel **1005**, a frame **1006**, a circuit board **1007**, and a battery **1008**. The touch panel **1003** and the display panel **1005** are connected to flexible printed circuit FPCs **1002** and **1004**, respectively. Active elements such as transistors are arranged on the circuit board **1007**. The battery **1008** may not be provided if the

display apparatus **1000** is not a portable device, or need not be provided in this position even if the display apparatus is a portable device. The pixel array **103** of the display apparatus **101** described above can be applied to the display panel **1005**. The display apparatus **101** functioning as the display panel **1005** is connected to the active element such as the transistor arranged on the circuit board **1007** to be operated. For example, the circuit board **1007** may correspond to the respective components of the above-described driving circuit.

(97) The display apparatus **1000** shown in FIG. **16** may be used for the display unit of a photoelectric conversion apparatus (image capturing apparatus) that includes an optical unit including a plurality of lenses and an image sensor that receives light having passed through the optical unit and photoelectrically converts the light into an electric signal. The photoelectric conversion apparatus may include a display unit which displays information acquired by the image sensor. The display unit may be a display unit exposed to the outside of the photoelectric conversion apparatus, or a display unit arranged in a viewfinder. The photoelectric conversion apparatus may be a digital camera or a digital video camera.

(98) FIG. **17** is a schematic view showing an example of a photoelectric conversion apparatus using the display apparatus **101** of this embodiment. A photoelectric conversion apparatus **1100** may include a viewfinder **1101**, a rear display **1102**, an operation unit **1103**, and a housing **1104**. The photoelectric conversion apparatus **1100** can be referred to as an image capturing apparatus. The display apparatus **101** described above can be applied to the viewfinder **1101** serving as the display unit. In this case, the display apparatus **101** may display not only an image to be captured, but also environment information, an image capturing instruction, and the like. The environment information may include the intensity of ambient light, the direction of ambient light, the moving speed of an object, the possibility that the object is blocked by a shielding object, or the like.

(99) Since the timing suitable for capturing an image is often a short time, it is better to display the information as quickly as possible. Therefore, the display apparatus **101** including an organic light emitting material such as an organic EL element as the light emitting element **201** can be used in the viewfinder **1101**. This is because the organic light emitting material has a high response speed. The display apparatus **101** using the organic light emitting material can be used more suitably than a liquid crystal display apparatus in the apparatuses that require a high display speed.

(100) The photoelectric conversion apparatus **1100** includes an optical unit (not shown). The optical unit includes a plurality of lenses and forms an image on a photoelectric conversion element (not shown), which receives light having passed through the optical unit, housed in the housing **1104**. It is possible to adjust the focus by adjusting the relative positions of the plurality of lenses. This operation can be performed automatically.

(101) The display apparatus **101** may be applied to the display unit of an electronic equipment. In this case, the display unit may have both a display function and an operation function. Examples of the mobile terminal include a mobile phone such as a smartphone, a tablet, and a head mounted display.

(102) FIG. **18** is a schematic view showing an example of an electronic equipment using the display apparatus **101** of this embodiment.

(103) An electronic equipment **1200** includes a display unit **1201**, an operation unit **1202**, and a housing **1203**. The housing **1203** may include a circuit, a printed board including the circuit, a battery, and a communication unit. The operation unit **1202** may be a button or a touch panel type sensing unit. The operation unit **1202** may be a biometrics unit that recognizes a fingerprint and releases a lock or the like. A portable device including a communication unit can also be called a communication equipment. The above-described display apparatus **101** can be applied to the display unit **1201**.

(104) FIGS. **19A** and **19B** are schematic views each showing an application example of a display apparatus using the display apparatus **101** of this embodiment. FIG. **19A** shows a display apparatus such as a television monitor or a PC monitor. A display apparatus **1300** includes a frame **1301** and a

display unit **1302**. The pixel array **103** of the display apparatus **101** described above can be applied to the display unit **1302**. The display apparatus **1300** may include a base **1303** that supports the frame **1301** and the display unit **1302**. The base **1303** is not limited to the form shown in FIG. **19A**. For example, the lower side of the frame **1301** may serve as the base **1303**. The frame **1301** and the display unit **1302** may be bent. The curvature radius may be between 5,000 mm (inclusive) and 6,000 mm (inclusive).

(105) FIG. **19B** is a schematic view showing another application example of the display apparatus using the display apparatus **101** of this embodiment. A display apparatus **1310** shown in FIG. **19B** is configured to be bendable, and is a so-called foldable display apparatus. The display apparatus **1310** includes a first display unit **1311**, a second display unit **1312**, a housing **1313**, and a bending point **1314**. The pixel array **103** of the display apparatus **101** described above can be applied to each of the first display unit **1311** and the second display unit **1312**. The first display unit **1311** and the second display unit **1312** may be one seamless display apparatus. The first display unit **1311** and the second display unit **1312** can be divided at the bending point. The first display unit **1311** and the second display unit **1312** may display different images, or one image may be displayed with the first display unit and the second display unit.

(106) FIG. **20** is a schematic view showing an example of an illumination apparatus using the display apparatus **101** of this embodiment. An illumination apparatus **1400** may include a housing **1401**, a light source **1402**, a circuit board **1403**, an optical film **1404**, and a light diffusion unit **1405**. The above-described display apparatus **101** can be applied to the light source **1402**. The optical film **1404** may be a filter that improves the color rendering property of the light source. The light diffusion unit **1405** can effectively diffuse light from the light source to illuminate a wide range for lighting up or the like. A cover may be provided in the outermost portion, as needed. The illumination apparatus **1400** may include both the optical film **1404** and the light diffusion unit **1405**, or may include only one of them.

(107) The illumination apparatus **1400** is, for example, an apparatus that illuminates a room. The illumination apparatus **1400** may emit light of white, day white, or any other color from blue to red. The illumination apparatus **1400** may include a light control circuit for controlling the light color. The illumination apparatus **1400** may include a power supply circuit connected to the display apparatus **101** which functions as the light source **1402**. The power supply circuit is a circuit that converts an AC voltage into a DC voltage. Note that white light has a color temperature of 4200K, and day-white light has a color temperature of 5000K. The illumination apparatus **1400** may also include a color filter. Further, the illumination apparatus **1400** may include a heat dissipation portion. The heat dissipation portion releases the heat in the apparatus to the outside of the apparatus, and examples thereof include a metal having high specific heat, liquid silicon, and the like.

(108) FIG. **21** is a schematic view showing an automobile including a tail lamp which is an example of the lighting unit for an automobile using the display apparatus **101** of this embodiment. An automobile **1500** includes a tail lamp **1501**, and may turn on the tail lamp **1501** when a brake operation or the like is performed. The display apparatus **101** of this embodiment may be used in a head lamp as the lighting unit for an automobile. The automobile is an example of a moving body, and the mobile body may be a ship, a drone, an aircraft, a railroad car, an industrial robot, or the like. The moving body may include a main body and a lighting unit provided in the main body. The lighting unit may inform the current position of the body.

(109) The above-described display apparatus **101** can be applied to the tail lamp **1501**. The tail lamp **1501** may include a protective member that protects the display apparatus **101** which functions as the tail lamp **1501**. The protective member has a certain degree of strength, and can be made from any material as long as it is transparent. The protective member may be made from polycarbonate or the like. Further, the protective member may be made from polycarbonate mixed with furandicarboxylic acid derivative, acrylonitrile derivative, or the like.

(110) The automobile **1500** may include a body **1503** and windows **1502** attached thereto. The window may be a window for checking the front or rear of the automobile, or may be a transparent display. The above-described display apparatus **101**, in which the light emitting layer **621** includes an organic light emitting material and functions as a light emitting apparatus, may be used in the transparent display. In this case, the components such as the electrodes included in the display apparatus **101** are formed by transparent members.

(111) Application examples of the display apparatus **101** according to the embodiments described above will be described with reference to FIGS. **22A** and **22B**. The display apparatus **101** is applicable to, for example, a system that can be worn as a wearable device such as smart glasses, an HMD (Head Mount Display), smart contact lenses, or the like. An image capturing display device that is used in such an application example includes an image capturing apparatus that can photoelectrically convert visible light and a light emitting apparatus that can emit visible light.

(112) FIG. **22A** illustrates a pair of glasses **1600** (smart glasses) according to an application example. An image capturing apparatus **1602** such as a CMOS sensor or an SPAD is arranged on the front surface side of a lens **1601** of the glasses **1600**. Also, the display apparatus **101** of each embodiment described above is arranged on the back surface side of the lens **1601**.

(113) The pair of glasses **1600** further includes a control apparatus **1603**. The control apparatus **1603** functions as a power supply that supplies power to the image capturing apparatus **1602** and the display apparatus **101** according to the embodiments. The control apparatus **1603** controls the operation of the image capturing apparatus **1602** and the operation of the display apparatus **101**. An optical system for focusing light to the image capturing apparatus **1602** is formed on the lens **1601**.

(114) FIG. **22B** illustrates a pair of glasses **1610** (smart glasses) according to another application example. The pair of glasses **1610** includes a control apparatus **1612**, and an image capturing apparatus corresponding to the image capturing apparatus **1602** and the display apparatus **101** are incorporated in the control apparatus **1612**. An optical system for projecting light emitted from the image capturing apparatus and the display apparatus **101** in the control apparatus **1612** is formed in a lens **1611**, and an image is projected onto the lens **1611**. In addition to functioning as a power supply that supplies power to the image capturing apparatus and the display apparatus **101**, the control apparatus **1612** also controls the operation of the image capturing apparatus and the operation of the display apparatus **101**. The control apparatus **1612** may include a line-of-sight detection unit that detects the line of sight of a wearer. Infrared light can be used for the line-of-sight detection. An infrared light emitting unit emits infrared light to the eyeball of a user who is gazing at a displayed image. When the emitted infrared light is reflected by the eyeball and detected by an image capturing unit including a light receiving element, a captured image of the eyeball can be obtained. Image quality degradation is reduced by providing a reduction means that reduces the light from the infrared light emitting unit to the display unit in a planar view.

(115) The line of sight of the user to the displayed image is detected from the captured image of the eyeball obtained by the image capturing operation using the infrared light. A known method can be arbitrarily applied for the line-of-sight detection using the captured eyeball image. As an example, a line-of-sight detection method based on Purkinje images caused by the reflection of the emitted light on the cornea can be used.

(116) More specifically, line-of-sight detection processing is performed based on a pupil-cornea reflection method. The line of sight of the user is detected by using the pupil-cornea reflection method to calculate a line-of-sight vector representing the direction (rotation angle) of the eyeball based on the image of the pupil and the Purkinje images included in the captured image of the eyeball.

(117) The display apparatus **101** according to this embodiment may include an image capturing apparatus including a light receiving element, and control a displayed image based on the line-of-sight information of the user obtained from the image capturing apparatus.

(118) More specifically, in the display apparatus **101**, a first field-of-view region which is gazed by

the user and a second field-of-view region other than the first field-of-view region are determined based on the line-of-sight information.

(119) The first field-of-view region and the second field-of-view region may be determined by a control apparatus of the display apparatus **101**. Alternatively, the first field-of-view region and the second field-of-view region may be determined by an external control apparatus and the display apparatus **101** may receive information corresponding to this determination. Control can be performed in the display region of the display apparatus **101** so that the display resolution of the first field-of-view region will be higher than the display resolution of the second field-of-view region. That is, the resolution of the second field-of-view region may be lowered more than the resolution of the first field-of-view region.

(120) In addition, the display region includes a first display region and a second display region different from the first display region, and a region with a high degree of priority is determined from the first display region and the second display region of the display region based on the line-of-sight information. The first field-of-view region and the second field-of-view region may be determined by the control apparatus of the display apparatus **101**. Alternatively, the first field-of-view region and the second field-of-view region may be determined by an external control apparatus and the display apparatus **101** may receive information corresponding to this determination. Control may be performed so that the resolution of a region with the high degree of priority will be set higher than the resolution of a region other than the region with the high degree of priority. That is, the resolution of a region with a relatively low degree of priority may be set low.

(121) Note that an AI may be used for the determination of the first field-of-view region and the region with the high degree of priority. The AI may be a model configured to estimate, from an image of the eyeball, the angle of the line of sight and the distance to an object as the target of the gaze by using the image of the eyeball and the direction actually gazed by the eyeball of the image as the teaching data. The display apparatus **101**, the image capturing apparatus, or an external apparatus may include the AI program. If the AI program is included in an external apparatus, information determined by the AI program will be transmitted to the display apparatus **101** by communication.

(122) In a case in which display control is to be performed based on visual recognition detection, the display apparatus **101** can be applied to a pair of smart glasses that further includes an image capturing apparatus configured to capture the outside. The smart glasses can display the captured outside information in real time.

(123) According to the present invention, it is possible to provide a technique advantageous in detecting the luminance of a light emitting element.

(124) While the present invention has been described with reference to exemplary embodiments, it is to be understood that the invention is not limited to the disclosed exemplary embodiments. The scope of the following claims is to be accorded the broadest interpretation so as to encompass all such modifications and equivalent structures and functions.

(125) This application claims the benefit of Japanese Patent Application No. 2021-138252, filed Aug. 26, 2021, which is hereby incorporated by reference herein in its entirety.

Claims

1. A display apparatus comprising a substrate in which a plurality of pixels are arranged, wherein each of the plurality of pixels comprises a light emitting element arranged above a first surface of the substrate, and a light receiving element arranged between the first surface and a second surface of the substrate on an opposite side of the first surface, wherein the light emitting element comprises a first electrode, a second electrode arranged between the first surface and the first electrode, and a light emitting layer arranged between the first electrode and the second electrode,

wherein in an orthogonal projection with respect to the first surface, the second electrode and the light receiving element at least partially overlap each other, wherein the second electrode transmits part of light generated in the light emitting layer, and wherein a transmittance of the second electrode to light generated in the light emitting layer is not less than 1% and not more than 20%.

2. The apparatus according to claim 1, wherein in an orthogonal projection with respect to a third surface orthogonal to the first surface, the light emitting element and the light receiving element do not overlap each other.
3. The apparatus according to claim 1, wherein an opening is provided in the second electrode.
4. The apparatus according to claim 3, wherein the opening is filled with a part of the light emitting layer or a light transmissive member.
5. The apparatus according to claim 3, wherein the second electrode has a stacked structure of a transparent electrode and a light shielding film in which the opening is provided.
6. The apparatus according to claim 1, wherein the plurality of pixels comprise a first pixel and a second pixel which emit light of different colors, respectively, and wherein a light receiving sensitivity of the light receiving element arranged in the first pixel and a light receiving sensitivity of the light receiving element arranged in the second pixel are different from each other.
7. The apparatus according to claim 6, wherein in the orthogonal projection with respect to the first surface, an area of the light receiving element arranged in the first pixel and an area of the light receiving element arranged in the second pixel are different from each other.
8. The apparatus according to claim 1, wherein (1) a light emitting circuit configured to drive the light emitting element and (2) a light receiving circuit configured to drive the light receiving element are further arranged in the substrate.
9. The apparatus according to claim 8, wherein the light emitting circuit comprises a capacitive element configured to hold a luminance signal corresponding to a luminance of light emission of the light emitting element, and wherein in the orthogonal projection with respect to the first surface, the light receiving element and the capacitive element do not overlap each other.
10. The apparatus according to claim 8, wherein an interlayer insulating film is arranged between the first surface and the first electrode, and wherein in the orthogonal projection with respect to the first surface, a light shielding layer is arranged in a region of the interlayer insulating film which overlaps an outer edge portion of each of the plurality of pixels.
11. The apparatus according to claim 10, wherein in the orthogonal projection to the first surface, an optical waveguide is arranged in a region of the interlayer insulating film which overlaps the light receiving element.
12. The apparatus according to claim 8, wherein an interlayer insulating film is arranged between the first surface and the first electrode, and wherein in the orthogonal projection with respect to the first surface, an optical waveguide is arranged in a region of the interlayer insulating film which overlaps the light receiving element.
13. A photoelectric conversion apparatus comprising: an optical unit comprising a plurality of lenses; an image sensor configured to receive light having passed through the optical unit; and a display unit configured to display an image, wherein the display unit is configured to display an image captured by the image sensor, and comprises the display apparatus according to claim 1.
14. An electric equipment comprising: a housing provided with a display unit; and a communication unit provided in the housing and configured to communicate with the outside, wherein the display unit comprises the display apparatus according to claim 1.
15. An illumination apparatus comprising a light source and at least one of a light diffusion unit and an optical film, wherein the light source comprises the display apparatus according to claim 1.
16. A moving body comprising a main body and a lighting unit provided in the main body, wherein the lighting unit comprises the display apparatus according to claim 1.
17. A wearable device comprising a display device configured to display an image, wherein the display device comprises the display apparatus according to claim 1.

18. A display apparatus comprising a substrate in which a plurality of pixels are arranged, wherein each of the plurality of pixels comprises a light emitting element arranged above a first surface of the substrate, and a light receiving element arranged between the first surface and a second surface of the substrate on an opposite side of the first surface, wherein the light emitting element comprises a first electrode, a second electrode arranged between the first surface and the first electrode, and a light emitting layer arranged between the first electrode and the second electrode, wherein in an orthogonal projection with respect to the first surface, the second electrode and the light receiving element at least partially overlap each other, wherein the substrate is a first substrate, and a second substrate arranged so as to face the second surface is further comprised, wherein at least a part of a light receiving circuit configured to drive the light receiving element is arranged in the first substrate, and wherein at least a part of a light emitting circuit configured to drive the light emitting element is arranged in the second substrate, wherein the light emitting circuit comprises a capacitive element configured to hold a luminance signal corresponding to a luminance of light emission of the light emitting element, wherein the capacitive element is arranged between the second surface and the second substrate, and wherein in the orthogonal projection with respect to the first surface, the light receiving element and the capacitive element at least partially overlap each other.

19. The apparatus according to claim 18, wherein the second electrode transmits part of light generated in the light emitting layer.

20. The apparatus according to claim 19, wherein a transmittance of the second electrode to light generated in the light emitting layer is not less than 1% and not more than 20%.

21. The apparatus according to claim 18, wherein in the orthogonal projection with respect to the first surface, an area occupied by the light receiving element and the light receiving circuit is larger than an area occupied by the light emitting circuit.

22. The apparatus according to claim 18, wherein a thickness of a gate insulating film of a transistor of the light receiving circuit arranged in the first substrate and a thickness of a gate insulating film of a transistor of the light emitting circuit arranged in the second substrate are different from each other.

23. The apparatus according to claim 18, wherein the plurality of pixels comprise a third pixel and a fourth pixel, and wherein the light receiving element arranged in the third pixel and the light receiving element arranged in the fourth pixel share the single light receiving circuit.

24. The apparatus according to claim 18, wherein the plurality of pixels comprise a third pixel and a fourth pixel, and wherein the third pixel and the fourth pixel share the single light receiving element.

25. The apparatus according to claim 23, wherein the third pixel and the fourth pixel emit light of different colors, respectively.
